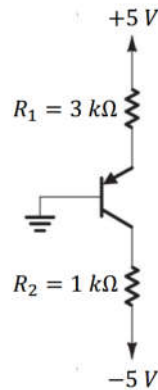


**Problem 1**

- a) Assuming BJT is in ACTIVE MODE  $\Rightarrow I_C = \beta I_B$ ,  $I_E = (\beta + 1)I_B$  and  $V_{EB} = V_{D0} = 0.7V$   
 BE KVL,  $5 = I_E \times 3k + V_{EB}$

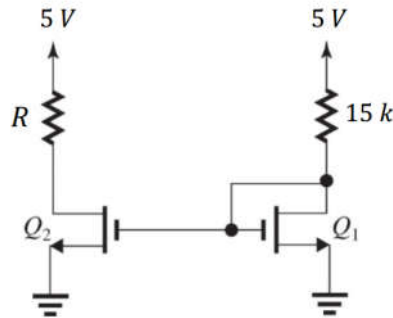
$$\Rightarrow I_E = 1.4333 \text{ mA}, I_C = \frac{\beta}{\beta + 1} I_E = 1.419 \text{ mA}$$

$$\Rightarrow V_E = 5 - 3k \times I_E = 0.7 \text{ V}, V_C = -5 + 1k \times I_C = -3.58 \text{ V}$$

$$V_{EC} = 4.28 \text{ V} > V_{D0} \Rightarrow \text{Correct Assumption}$$

- b) Transistor stays in ACTIVE MODE until  $V_{EC} = V_{D0} = 0.7 \Rightarrow V_C = 0V$ . Then,

$$R_2 = \frac{V_C + 5}{I_C} = \frac{5}{1.419 \text{ mA}} = 3.523 \text{ k}\Omega$$

**Problem 2****important**For Q1,  $V_{GD1} = 0 < V_t \Rightarrow Q1$  is at SATURATION

$$\begin{aligned}
 \frac{5 - V_{D1}}{15k} &= \frac{1}{2} \mu_n C_{ox} \frac{W}{L} V_{OV1}^2 \\
 \Rightarrow \frac{5 - V_{GS1}}{15k} &= \frac{1}{2} \mu_n C_{ox} \frac{W}{L} V_{OV1}^2 \\
 \Rightarrow \frac{5 - V_{OV1} - V_t}{15k} &= \frac{1}{2} \mu_n C_{ox} \frac{W}{L} V_{OV1}^2 \\
 30 V_{OV1}^2 + V_{OV1} - 4 &= 0 \\
 \Rightarrow V_{OV1} &= 0.34886 V, \quad \text{---} 0.3822 \\
 \Rightarrow V_{GS1} = V_{G1} = V_{G2} = V_{GS2} = V_{OV1} + V_t &= 1.34886 V
 \end{aligned}$$

Here,

**important**

$V_{GS1} = V_{GS2} \Rightarrow I_{D1} = I_{D2} \text{ and } V_{OV1} = V_{OV2}$

Now, Q2 is at the edge of SATURATION  $\Rightarrow V_{GS2} - V_t = V_{OV2} = V_{DS2}$ 

Then,

$$\begin{aligned}
 I_{D2} &= \frac{5 - V_{DS2}}{R} \Rightarrow \frac{1}{2} \mu_n C_{ox} \frac{W}{L} V_{OV1}^2 = \frac{5 - V_{OV1}}{R} \\
 \Rightarrow R &= 19.1 K\Omega
 \end{aligned}$$